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# Electrical and SERS detection of disulfide-mediated dimerization in single-molecule benzene-1,4-dithiol junctions†

Jueting Zheng,<sup>‡</sup> Junyang Liu,<sup>‡</sup> Yijing Zhuo, Ruihao Li, Xi Jin, Yang Yang,<sup>\*</sup> Zhao-Bin Chen, Jia Shi, Zongyuan Xiao, Wenjing Hong<sup>‡</sup> and Zhong-qun Tian<sup>‡</sup>

We applied a combination of mechanically controllable break junction (MCBJ) and *in situ* surface enhanced Raman spectroscopy (SERS) methods to investigate the long-standing single-molecule conductance discrepancy of prototypical benzene-1,4-dithiol (BDT) junctions. Single-molecule conductance characterization, together with configuration analysis of the molecular junction, suggested that disulfide-mediated dimerization of BDT contributed to the low conductance feature, which was further verified by the detection of S–S bond formation through *in situ* SERS characterization. Control experiments demonstrated that the disulfide-mediated dimerization could be tuned *via* the chemical inhibitor. Our findings suggest that a combined electrical and SERS method is capable of probing chemical reactions at the single-molecule level.

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## Introduction

During the past decade, charge transport in molecular electronics has been explored through various types of single-molecule junctions.<sup>1–10</sup> Among these molecules, benzene-1,4-dithiol (BDT) has widely attracted interest as it has been a well studied model junction over the past few decades.<sup>1,11–13</sup> Interestingly, the reported single-molecule conductances for BDT are split into two groups: a high conductance feature at around  $10^{-1}$  to  $10^{-2} G_0$ ,<sup>3,14,15</sup> and a low conductance feature at around  $10^{-3}$  to  $10^{-4} G_0$ ,<sup>1,16–18</sup> where  $G_0$  is the conductance quantum. To resolve the conductance discrepancy of BDT, a number of experimental and theoretical efforts have been made to correlate the configuration of BDT molecular junctions with measured conductance values. Kim *et al.* attributed the observed low conductance to a tilted configuration,<sup>16</sup> while Kaneko *et al.* attributed the low conductance to the hollow and atop adsorption-site geometries.<sup>18</sup> Bruot *et al.* demonstrated that the stretching of a BDT single-molecule junction causes a strain-induced shift of the highest occupied molecular orbital (HOMO), which may influence the conductance.<sup>19</sup> Despite these intensive efforts, experimental detection of the molecular

configurations correlating to low conductance characterization remains considerably challenging.

Surface enhanced Raman spectroscopy (SERS) leads to the detection of the fingerprint of probed molecules with single-molecule sensitivity.<sup>20–22</sup> Furthermore, recent developments of single-molecule junction techniques such as configuration analysis provide new characterization tools to investigate charge transport through single-molecule junctions beyond the conductance.<sup>23–28</sup> The combined MCBJ and SERS (MCBJ-SERS)<sup>29,30</sup> method allows simultaneous electrical and spectroscopic characterizations of single-molecule junctions,<sup>31–34</sup> which also offers a new opportunity to unveil the nature of the low conductance feature in single-molecule BDT junctions.

In this communication, we investigated the configuration of a BDT single-molecule junction using the MCBJ-SERS method. The single-molecule break junction measurement suggests that 4,4'-disulfaneyldibenzenethiol (**dimeric-BDT**) appeared spontaneously during the conductance measurement of the BDT junction. Configurational analysis suggests that **dimeric-BDT** rather than BDT should be responsible for the observed low conductance. The configurational evolution is also supported by observation of an S–S bond signal in the SERS characterization, with the parallel BDT and **dimeric-BDT** junction contributing to the high conductance, while the **dimeric-BDT** junction contributes to the low conductance.

## Results and discussion

For the single-molecule conductance measurements, 0.02 mM BDT solution was freshly prepared in a mixed ethanol (EtOH) and 1,3,5-trimethylbenzene (TMB) solvent (*v/v* = 1 : 49). Then

State Key Laboratory of Physical Chemistry of Solid Surfaces, College of Chemistry and Chemical Engineering, Pen-Tung Sah Institute of Micro-Nano Science and Technology, Graphene Industry and Engineering Research Institute, iChEM, Xiamen University, Xiamen 361005, China. E-mail: whong@xmu.edu.cn; yangyang@xmu.edu.cn

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‡ These authors contributed equally.



the conductance measurements were carried out using our homebuilt MCBJ-SERS setup (Fig. 1a) following a conventional MCBJ protocol.<sup>35–38</sup> ~5000 conductance-distance traces were recorded for the conductance measurement of **BDT**, and Fig. 1b shows typical individual traces. It was found that most of the individual traces exhibited both high and low conductance plateaus, while there were also some curves showing only one high conductance or low conductance plateau. Besides this, there is a very small number of traces having no plateau. In comparison with control experiments, the conductance measurement in solvent without the target molecule shows direct tunnelling character without a molecular plateau, as shown in Fig. S1 (see ESI Section 1†), suggesting that the high conductance and low conductance plateaus both come from **BDT** molecules.

The conductance histograms constructed from different types of trace are shown in Fig. 1c. The blue histogram constructed from all traces without data selection shows two pronounced peaks at  $10^{-1.32 \pm 0.42} G_0$  (high conductance) and  $10^{-3.68 \pm 0.60} G_0$  (low conductance), while the conductance histogram constructed from traces with only one conductance feature shows only one conductance peak (red and green histograms in the inset of Fig. 1c). The observed high conductance value is in agreement with some previous reports of **BDT** single-molecule junctions,<sup>14–16,39</sup> while the low conductance

value herein also agrees with some other reported conductance or secondary conductance features for **BDT**.<sup>1,16–18,40</sup>

To correlate the conductance and the distance between the two electrodes for high conductance and low conductance features, a 2D conductance-distance histogram was constructed from all of the traces. As shown in Fig. 2a, two prominent conductance clouds are found. The displacement distributions for the high conductance and low conductance features were analysed as follows. For the high conductance plateau, the length was defined as the distance between the points where the conductance fell in between  $10^{-0.3} G_0 \sim 10^{-2.5} G_0$ , while for the low conductance plateau it was defined as that between  $10^{-0.3} G_0 \sim 10^{-4.6} G_0$ . As shown in Fig. 2b, the most probable relative displacement for low conductance ( $0.72 \pm 0.20$  nm) is significantly longer than that of high conductance ( $0.39 \pm 0.16$  nm). The 0.33 nm difference in displacement suggests that low conductance and high conductance come from different molecular configurations. Considering that the snap-back distance is approximately 0.5 nm for a gold atomic contact,<sup>35</sup> the length of the corresponding microscopic configuration for high conductance is 0.89 (0.39 plus 0.5) nm, which is close to the length of **BDT** (0.846 nm),<sup>18</sup> thus suggesting that high conductance comes from a perpendicularly orientated configuration. More interestingly, taking into account the snap-back distance, for the low conductance the most probable displacement reaches 1.22 (0.72 plus 0.5) nm, which is around 0.4 nm longer than the length of **BDT**.<sup>16</sup> This significant difference implies that the origin of the low conductance goes beyond a single-molecule **BDT** junction.



Fig. 1 (a) Schematic of the MCBJ-SERS setup and the molecular structures of **BDT** and dimeric-**BDT**. (b) Four types of typical trace recorded using the MCBJ technique, consisting of ones with two conductance plateaus (purple), high conductance only (red), low conductance only (green), and no plateau (black). (c) Conductance histogram constructed from ~5000 conductance-distance traces (blue, 4720 curves, offset by -10 000 counts for comparison), as well as the conditional histograms that are constructed from those traces with two conductance plateaus (purple, 4508 curves, offset by -10 000 counts for comparison), high conductance only (red, 134 curves), low conductance only (green, 67 curves) and no plateau (black, 11 curves), respectively. Inset: expansion of the red, green, and black conductance histograms with the scale shown from -100 to 1400 for better demonstration.

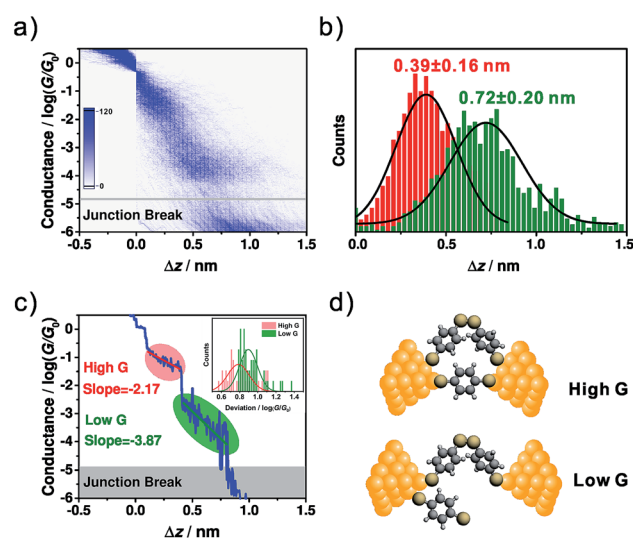


Fig. 2 (a) The 2D conductance-distance histogram constructed from ~5000 individual traces. (b) The relative displacement distributions for high conductance (red) and low conductance (green). (c) The master curve built from (a). Inset: the distributions of the conductance deviations from the master curve within the high conductance (red) and low conductance (green) regimes. Bin size: 0.02. (d) The hypothesized evolution of the microscopic configuration as the conductance evolves from high conductance to low conductance.



A detailed distribution analysis of the different types of trace also indicated that both high conductance and low conductance plateaus appear simultaneously in 95.5% of the conductance-distance traces (see ESI Section 2 and Table S1† for more details). In contrast, the percentages of the traces with only high conductance or low conductance plateaus are 2.84% and 1.42%, respectively. There is a possible hypothesis that the low conductance comes from 4,4'-disulfaneyldibenzenethiol, *i.e.*, **dimeric-BDT**, and the continuous appearance of two conductance features suggests the presence of parallel **BDT** and **dimeric-BDT** molecular junctions for the high conductance regime.

Fig. 1a shows the molecular structure of **dimeric-BDT**, where two **BDT** components are connected by a rotatable S-S single bond. Under ambient conditions, it has been demonstrated that **BDT** can convert to **dimeric-BDT** spontaneously as a result of oxidative dimerization.<sup>41</sup> We estimated the effective conductive length of a **dimeric-BDT** molecule through density functional theory (DFT) calculation. As shown in Fig. S3,† the distance between the anchored gold atoms from the opposite electrodes was estimated to be 1.32 nm, which agrees well with our result that the length of the corresponding configuration for low conductance is 1.22 nm. Thus, Fig. 2d gives the framework of our hypothesis as follows: for the high conductance plateau, there is an Au/**dimeric-BDT**/Au single-molecule junction in parallel to the Au/**BDT**/Au single-molecule junction. As the electrode pair is stretched gradually, the Au/**BDT**/Au junction breaks firstly, and consequently the Au/**dimeric-BDT**/Au junction dominates charge transport and contributes to the low conductance plateau, which leads to the simultaneous appearance of high conductance and low conductance in individual traces.

To further investigate the configurational evolution behind the observed high conductance and low conductance, a master curve, which represents the most probable conductance-distance trace,<sup>35</sup> was extracted and is shown in Fig. 2c. Here, the regimes for high conductance and low conductance are marked with red and green circles, respectively. The master curves and conductance variation analysis (Fig. 2c inset)<sup>35</sup> indicated that the conductance fluctuation in the low conductance regime is much larger than that of the high conductance one. The larger conductance fluctuation implies that the structure of the molecular junction for low conductance has more freedom in its configurational variation, which may come from the flexibility of the S-S single bond formed in **dimeric-BDT**. We further analysed the displacement dependence of conductance in the master curve. For the high and low conductance plateaus of the master curve, the changing rates of the conductance along with the junction length were found to be  $-2.17 \log(G/G_0)/\text{nm}$  for the high conductance regime (red line) and  $-3.87 \log(G/G_0)/\text{nm}$  for the low conductance regime (green line), as shown in Fig. 2c. The deviation levels of the high and low conductance region were given by a Gaussian fit of the conductance deviation distributions (Fig. 2c inset). The deviation level of the high conductance regime agrees well with a previous report on rigid conjugated molecules with thiols as anchoring groups.<sup>35</sup> Moreover, the larger deviation level of the

low conductance regime indicates that the configuration for high conductance is more rigid than that of low conductance, which is consistent with the existence of **BDT** and **dimeric-BDT**.

The use of *in situ* SERS measurements offers a complementary approach besides single-molecule conductance characterization to verify our hypothesis of configurational evolution of the **BDT** junctions.

To detect the presence of an S-S bond for **dimeric-BDT**, we placed the MCBJ set-up under a Raman microscope with a 785 nm laser to activate the SPR inside the nanogap, as shown in Fig. 1a and S4 in the ESI.†

To avoid the appearance of a fluorescence background in the SERS spectra, a 785 nm laser was adopted. For the configuration of two facing nano-electrodes with nanometre-sized separation, it has been demonstrated that surface plasmon resonance (SPR) would be triggered inside the nano-gap when the electrode configuration was irradiated using a 785 nm laser.<sup>42-44</sup> The SPR then greatly enhances the Raman signals, making it possible to get the signal of a single molecule. To perform *in situ* SERS characterization, the MCBJ setup was placed on a home-built platform under the Raman microscope. The laser spot was firstly positioned at different sites of the electrode pair to analyse the origin of the SERS signal, as shown in Fig. 3a. We measured the SERS signals at three different sites: the gap area (spot 1), the edge of the gap (spot 2), and the Au wire surface outside the gap (spot 3). For the signals collected from spot 2 and 3, the SERS intensity decreased significantly compared to that from spot 1. This observation agrees with previous reports,<sup>29,31,34</sup> which indicates that for the molecules trapped between the two electrodes, the enhancement factor of the SERS signal increases significantly. Because the gold atoms constituting the Au/**BDT**/Au junction are the closest ones inside the gap area, the electromagnetic field achieved a maximum in the area of the Au/**BDT**/Au junction. As a result, **BDT** from the junction area has the largest enhancement factor during SERS characterization. Thus, among the molecules that are trapped within the nanogap, it can be further inferred that the Au/**BDT**/Au junction, rather than **BDT** molecules that are adsorbed on just one electrode, gives the major contribution to the obtained SERS signal.

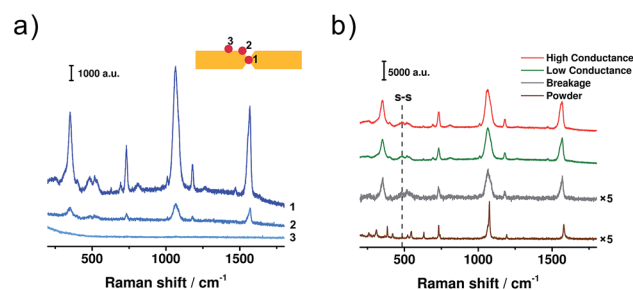


Fig. 3 (a) SERS spectra of **BDT** collected from different sites of the electrode pair. Inset: the locations of the laser spot. (b) SERS spectra collected when the molecular junction was mechanically controlled at the regimes of high conductance (red), low conductance (green), and breakage (grey), respectively. An ordinary Raman spectrum of **BDT** powder (brown) is displayed for comparison. Laser excitation: 785 nm.



Then we collected SERS spectra when the **BDT** single-molecule junction was controlled at the regimes of high conductance, low conductance and breakage, respectively, as shown in Fig. 3b. For these MCBJ-SERS spectra, the major bands can be assigned to the C–S stretching mode ( $354\text{ cm}^{-1}$ ,  $\nu_{6a}$ ), ring breathing mode ( $1067\text{ cm}^{-1}$ ,  $\nu_1$ ), C=C stretching mode ( $1569\text{ cm}^{-1}$ ,  $\nu_{8a}$ ),<sup>18,45,46</sup> as well as the ring mode of 7a ( $730\text{ cm}^{-1}$ ) and 9a ( $1180\text{ cm}^{-1}$ ).<sup>47</sup> For comparison, the ordinary Raman spectrum of bare **BDT** powder was collected and is shown in Fig. 3b. In the ordinary Raman spectrum, the  $\nu_1$  and  $\nu_{8a}$  modes appear at  $1075$  and  $1579\text{ cm}^{-1}$  (see Fig. S5 in ESI† for details), while in the MCBJ-SERS spectra they are red-shifted to  $1064$  and  $1569\text{ cm}^{-1}$ , respectively. Through a combination of SERS study and quantum chemical calculation, we have demonstrated that the frequency shifts of these two modes can be used as a signature to verify the formation of a Au/**BDT**/Au junction.<sup>48,49</sup> Thus the red shift observed here further confirms our inference that the Au/**BDT**/Au junction is responsible for the collected SERS signals. More significantly, a distinct peak appeared at  $485\text{ cm}^{-1}$  during the SERS characterization, as highlighted by the dashed line in Fig. 3b. This peak has been recognized as the vibrational mode of the S–S bond,<sup>50,51</sup> thus indicating the presence of **dimeric-BDT** during the conductance measurements. More interestingly, as shown in Fig. 3b, these two peaks appeared in both the regimes of high conductance and low conductance. Therefore, although at the regime of high conductance the conduction is dominated by **BDT**, the **dimeric-BDT** junction is also present at such a state, giving rise to the microscopic configuration as sketched in Fig. 2d.

To further test our hypothesis that the low conductance comes from the **dimeric-BDT** junction, two control experiments were performed. The first one was tuning the formation probability of **dimeric-BDT**. Herein,  $0.1\text{ mM}$  tris(2-carboxyethyl) phosphine hydrochloride (TCEP), a reagent widely used to disrupt disulfide bonds,<sup>52</sup> was prepared in a mixed solvent of EtOH and TMB ( $v/v = 1:9$ ), and then added into the **BDT** solution that was to be assayed through single-molecule conductance measurements. It was found that the intensity of the high conductance peak remained unchanged after adding TCEP (Fig. 4a). In contrast, the low conductance peak in the 1D conductance histogram (Fig. 4a), as well as the intensity cloud of low conductance in the 2D conductance-distance histogram (Fig. 4b), became inconspicuous. This observation indicates that TCEP

prevents the occurrence of the configuration that accounts for low conductance, which agrees well with the existence of **dimeric-BDT**. Secondly, the possibility that the low conductance feature results from the formation of a  $\pi$ - $\pi$  stacking configuration needs to be eliminated.<sup>53,54</sup> We employed pentane-1,5-dithiol (PDT) as the probe molecule since it has no  $\pi$  conjugated component. Thus, a  $\pi$ - $\pi$  stacking configuration could not be formed during the measurement, while the disulfide configuration was still formed and caused a lower conductance. It was found that the 1D conductance histogram for PDT exhibited two conductance peaks, similar to that of **BDT**. Moreover, the lower one can be restrained using TCEP as well (see Section 8 in ESI† for details). Therefore, for both **BDT** and PDT, it is the disulfide configuration, rather than the  $\pi$ - $\pi$  stacking configuration,<sup>53,54</sup> that should be ascribed to the low conductance.

## Conclusions

In summary, we investigated the charge transport through a **BDT** single-molecule junction with a combined MCBJ and *in situ* SERS approach. Two distinct conductance features were found to appear simultaneously in the single-molecule conductance measurements. It was also found that there is a  $\sim 0.33\text{ nm}$  difference in the displacement between the lengths of the high conductance and low conductance plateaus. The length for the low conductance feature is significantly longer than the molecular length of **BDT**, but is in agreement with that of the **dimeric-BDT** junction. To further confirm the presence of **dimeric-BDT**, the signal of an S–S single bond was observed using *in situ* SERS for both the high and low conductance states. These results revealed that it is **dimeric-BDT**, rather than **BDT** itself, that contributes to the low conductance feature. Control experiments demonstrate that disulfide-mediated dimerization could be tuned *via* the chemical inhibitor. Our findings suggest that the detection of a chemical reaction will also contribute to the discrepancy in single-molecule conductance measurements, which provide a novel avenue for the design and fabrication of molecular devices at the single-molecule scale.

## Conflicts of interest

There are no conflicts to declare.

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Fig. 4 (a) Conductance histograms of **BDT** before (blue) and after (red) the addition of TCEP. (b) 2D conductance-distance histogram of **BDT** after the addition of TCEP.



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